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Vishay Semiconductor/Opto Division
VSLY5850

For any questions, you can email us directly:
sales@integrated-circuit.com

High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology

22114

DESCRIPTION

As part of the SurfLight™ portfolio, the VSLY5850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted plastic package, with a parabolic lens.

FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Leads with stand-off
- Peak wavelength: λ_p = 850 nm
- High reliability
- High radiant power
- High radiant intensity
- Narrow angle of half intensity: φ = ± 3°
- Suitable for high pulse current operation
- Good spectral matching with CMOS cameras
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE
GREEN (5-2008)

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- Smoke-automatic fire detectors
- IR Flash

PRODUCT SUMMARY				
COMPONENT	**I_e (mW/sr)**	**φ (deg)**	**λ_p (nm)**	**t_r (ns)**
VSLY5850	600	± 3	850	10

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	**PACKAGING**	**REMARKS**	**PACKAGE FORM**
VSLY5850	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 µs	I_{FM}	200	mA
Surge forward current	t_p = 100 µs	I_{FSM}	1	A
Power dissipation		P_V	190	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R_{thJA}	230	K/W

For technical questions, contact: emittertechsupport@vishay.com
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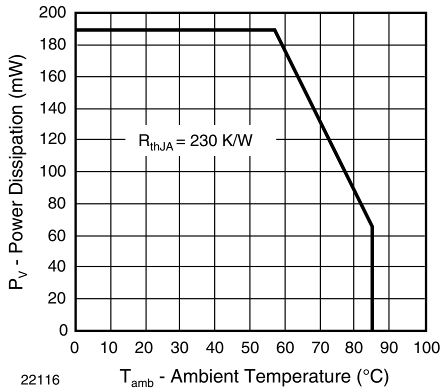

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

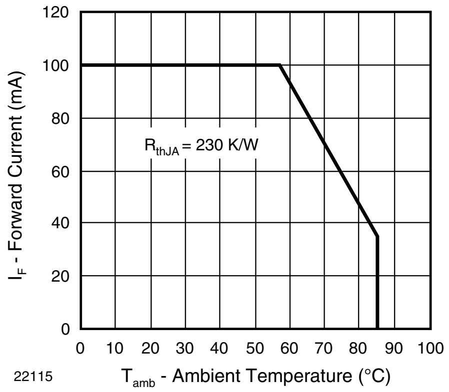

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F		1.65	1.9	V
	I_F = 1 A, t_p = 100 μs	V_F		2.9		V
Temperature coefficient of V_F	I_F = 1 mA	TK_{VF}		- 1.45		mV/K
	I_F = 10 mA	TK_{VF}		- 1.25		mV/K
Reverse current		I_R	not designed for reverse operation			μA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_j		125		pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	300	600	900	mW/sr
	I_F = 1 A, t_p = 100 μs	I_e		5100		mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕ_e		55		mW
Temperature coefficient of ϕ_e	I_F = 100 mA	$TK\phi_e$		- 0.35		%/K
Angle of half intensity		φ		± 3		deg
Peak wavelength	I_F = 100 mA	λ_p	840	850	870	nm
Spectral bandwidth	I_F = 100 mA	Δλ		30		nm
Temperature coefficient of λ_p	I_F = 100 mA	$TK\lambda_p$		0.25		nm/K
Rise time	I_F = 100 mA	t_r		10		ns
Fall time	I_F = 100 mA	t_f		10		ns

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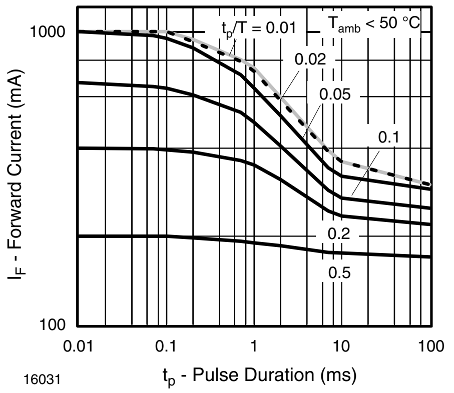

Fig. 3 - Pulse Forward Current vs. Pulse Duration

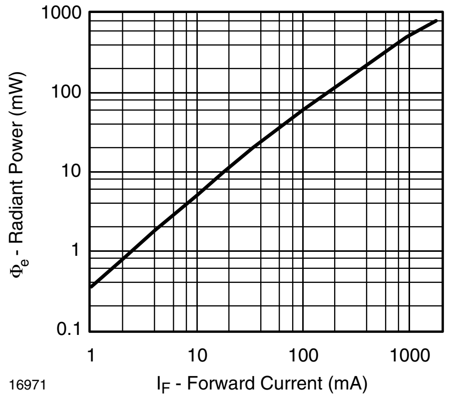

Fig. 6 - Radiant Power vs. Forward Current

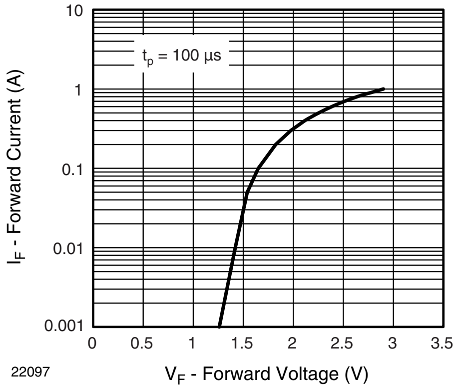

Fig. 4 - Forward Current vs. Forward Voltage

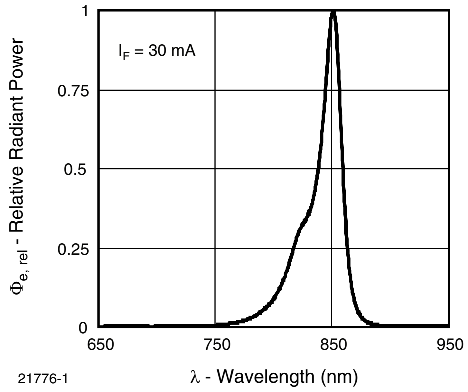

Fig. 7 - Relative Radiant Power vs. Wavelength

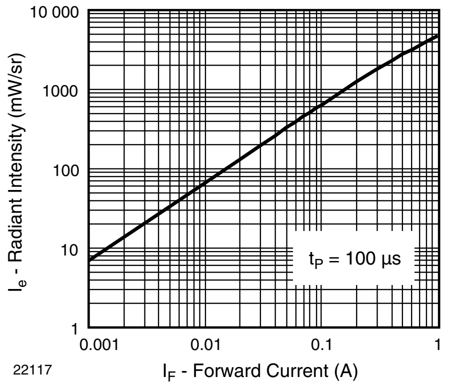

Fig. 5 - Radiant Intensity vs. Forward Current

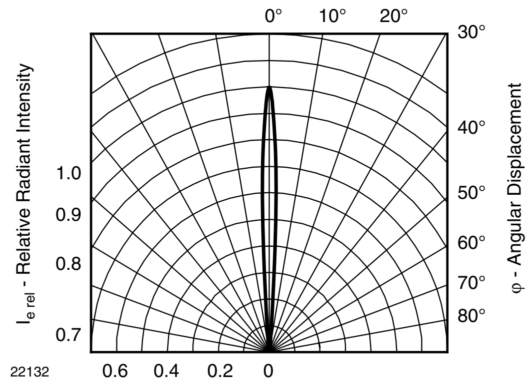

Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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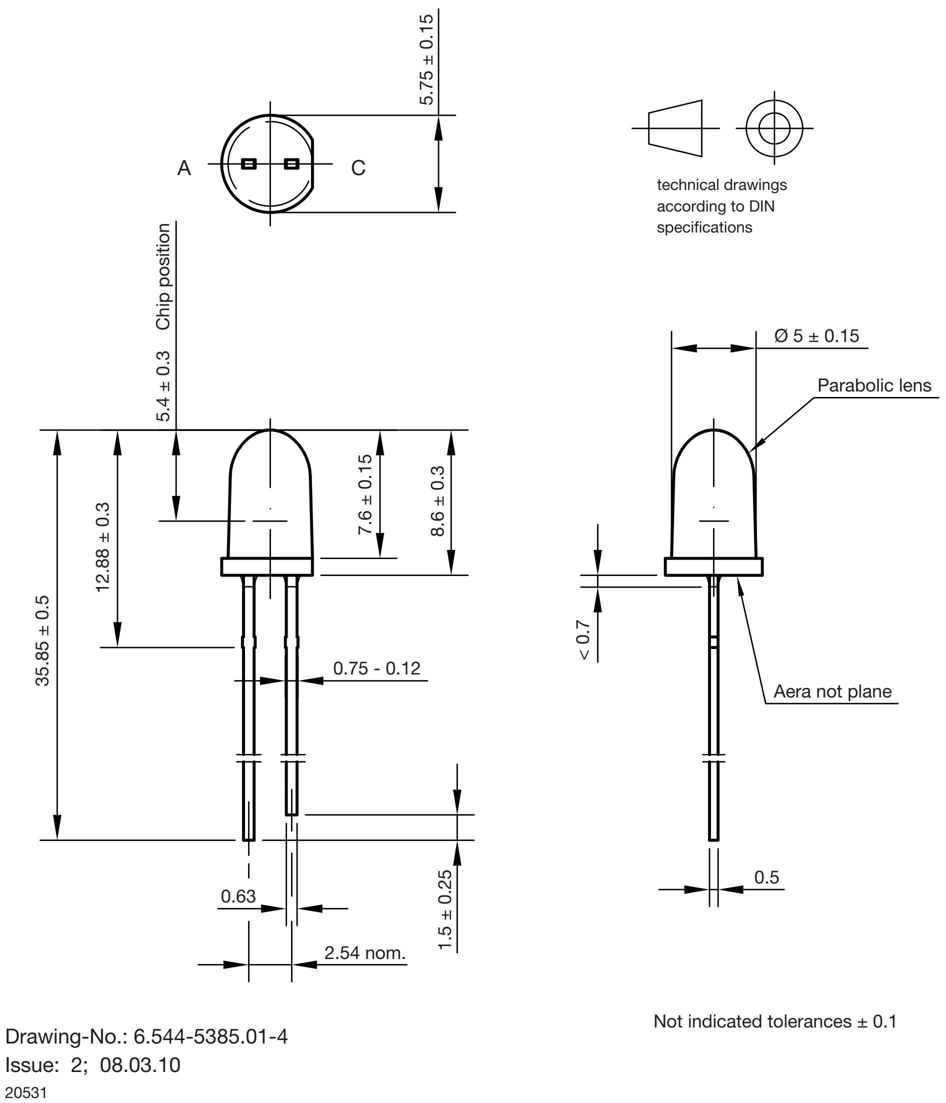
PACKAGE DIMENSIONS in millimeters



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